ON Semiconductor

Is Now

Onsemi

To learn more about onsemi[™], please visit our website at <u>www.onsemi.com</u>

onsemi and ONSEMI: and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application is provided for uses as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi roducts for any such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs

Hex Schmitt Trigger

The MC14106B hex Schmitt Trigger is constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. These devices find primary use where low power dissipation and/or high noise immunity is desired. The MC14106B may be used in place of the MC14069UB hex inverter for enhanced noise immunity or to "square up" slowly changing waveforms.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

Features

- Increased Hysteresis Voltage Over the MC14584B
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low–power TTL Loads or One Low–power Schottky TTL Load Over the Rated Temperature Range
- Pin-for-Pin Replacement for CD40106B and MM74C14
- Can Be Used to Replace the MC14584B or MC14069UB
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

| Symbol | Parameter | Value | Unit |
|------------------------------------|--|-------------------------------|------|
| V _{DD} | DC Supply Voltage Range | -0.5 to +18.0 | V |
| V _{in} , V _{out} | Input or Output Voltage Range (DC or Transient) | –0.5 to V _{DD} + 0.5 | V |
| I _{in} , I _{out} | Input or Output Current (DC or Transient) per Pin | ±10 | mA |
| P _D | Power Dissipation, per Package (Note 1) | 500 | mW |
| T _A | Ambient Temperature Range | -55 to +125 | °C |
| T _{stg} | Storage Temperature Range | -65 to +150 | °C |
| TL | Lead Temperature (8–Second Soldering) | 260 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Packages: -7.0 mW/°C From 65°C To 125°C



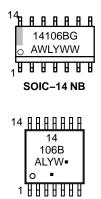
ON Semiconductor®

http://onsemi.com



SOIC-14 NB D SUFFIX CASE 751A TSSOP-14 DT SUFFIX CASE 948G

MARKING DIAGRAMS



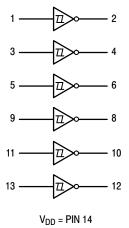
TSSOP-14

A = Assembly Location WL, L = Wafer Lot YY, Y = Year WW, W = Work Week G or • = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.



V_{SS} = PIN 7



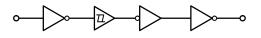


Figure 2. Equivalent Circuit Schematic (1/6 of Circuit Shown)

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-----------------|-------------------------|-----------------------|
| MC14106BDG | SOIC-14 NB (Pb-Free) | 55 Units / Rail |
| NLV14106BDG* | SOIC-14 NB (Pb-Free) | 55 Units / Rail |
| MC14106BDR2G | SOIC-14 NB (Pb-Free) | 2500 / Tape & Reel |
| NLV14106BDR2G* | SOIC-14 NB (Pb-Free) | 2500 / Tape & Reel |
| MC14106BDTR2G | TSSOP-14 (Pb-Free) | 2500 / Tape & Reel |
| NLV14106BDTR2G* | TSSOP-14 (Pb-Free) | 2500 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP

Capable.

| ELECTRICAL CHARACTERISTICS | (Voltages Referenced to V _{SS}) |
|-----------------------------------|---|
|-----------------------------------|---|

| | | | | -55 | 5°C | | 25°C | | 12 | 5°C | |
|---|-----------|-------------------------------|------------------------|-------------------------------|----------------------|-------------------------------|---|----------------------|-------------------------------|----------------------|------|
| Characteristic | | Symbol | V _{DD} Vdc | Min | Мах | Min | Typ (Note 2) | Max | Min | Max | Unit |
| Output Voltage V _{in} = V _{DD} | "0" Level | V _{OL} | 5.0 10 15 | - - - | 0.05 0.05 0.05 | - - - | 0 0 0 | 0.05 0.05 0.05 | - - - | 0.05 0.05 0.05 | Vdc |
| V _{in} = 0 | "1" Level | V _{OH} | 5.0 10 15 | 4.95 9.95 14.95 | - - - | 4.95 9.95 14.95 | 5.0 10 15 | - - - | 4.95 9.95 14.95 | _ _ _ | Vdc |
| Hysteresis Voltage | | V _H ⁽⁵⁾ | 5.0 10 15 | 0.3 1.2 1.6 | 2.0 3.4 5.0 | 0.3 1.2 1.6 | 1.1 1.7 2.1 | 2.0 3.4 5.0 | 0.3 1.2 1.6 | 2.0 3.4 5.0 | Vdc |
| Threshold Voltage Positive–Going | | V _{T+} | 5.0 10 15 | 2.2 4.6 6.8 | 3.6 7.1 10.8 | 2.2 4.6 6.8 | 2.9 5.9 8.8 | 3.6 7.1 10.8 | 2.2 4.6 6.8 | 3.6 7.1 10.8 | Vdc |
| Negative-Going | | V _{T-} | 5.0 10 15 | 0.9 2.5 4.0 | 2.8 5.2 7.4 | 0.9 2.5 4.0 | 1.9 3.9 5.8 | 2.8 5.2 7.4 | 0.9 2.5 4.0 | 2.8 5.2 7.4 | Vdc |
| Output Drive Current $(V_{OH} = 2.5 \text{ Vdc})$ $(V_{OH} = 4.6 \text{ Vdc})$ $(V_{OH} = 9.5 \text{ Vdc})$ $(V_{OH} = 13.5 \text{ Vdc})$ | Source | I _{ОН} | 5.0 5.0 10 15 | -3.0 -0.64 -1.6 -4.2 | | -2.4 -0.51 -1.3 -3.4 | -4.2 -0.88 -2.25 -8.8 | - - - | -1.7 -0.36 -0.9 -2.4 | | mAdo |
| $(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$ | Sink | I _{OL} | 5.0 10 15 | 0.64 1.6 4.2 | - - - | 0.51 1.3 3.4 | 0.88 2.25 8.8 | - - - | 0.36 0.9 2.4 | - - - | mAdo |
| Input Current | | l _{in} | 15 | - | ±0.1 | - | ±0.00001 | ±0.1 | - | ±1.0 | μAdc |
| Input Capacitance (V _{in} = 0) | | C _{in} | - | - | - | - | 5.0 | 7.5 | - | - | pF |
| Quiescent Current (Per Package) | | I _{DD} | 5.0 10 15 | - - - | 0.25 0.5 1.0 | - - - | 0.0005 0.0010 0.0015 | 0.25 0.5 1.0 | _ _ _ | 7.5 15 30 | μAdc |
| Total Supply Current (Notes (Dynamic plus Quiescer Per Package) (C _L = 50 pF on all outpu buffers switching) | nt, | ΙŢ | 5.0 10 15 | | | $I_{T} = (3)$ | 1.8 μΑ/kHz) f 3.6 μΑ/kHz) f 5.4 μΑ/kHz) f | + I _{DD} | | | μAdc |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

3. The formulas given are for the typical characteristics only at 25°C.

4. To calculate total supply current at loads other than 50 pF: $I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk where } I_T \text{ is in } \mu\text{A} \text{ (per package)}, C_L \text{ in pF, } V = (V_{DD} - V_{SS}) \text{ in volts, f in kHz is input frequency, and}$ k = 0.001.

5. $V_H = V_{T+} - V_{T-}$ (But maximum variation of V_H is specified as less that $V_{T+max} - V_{T-min}$).

SWITCHING CHARACTERISTICS (CL = 50 pF, TA = 25° C)

| Characteristic | Symbol | V _{DD} Vdc | Min | Typ (Note 6) | Max | Unit |
|------------------------|-------------------------------------|------------------------|-----|------------------------|-----|------|
| Output Rise Time | t _{TLH} | 5.0 | - | 100 | 200 | ns |
| | | 10 | - | 50 | 100 | |
| | | 15 | - | 40 | 80 | |
| Output Fall Time | t _{THL} | 5.0 | - | 100 | 200 | ns |
| | | 10 | - | 50 | 100 | |
| | | 15 | - | 40 | 80 | |
| Propagation Delay Time | t _{PLH} , t _{PHL} | 5.0 | - | 125 | 250 | ns |
| | | 10 | _ | 50 | 100 | |
| | | 15 | — | 40 | 80 | |

6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

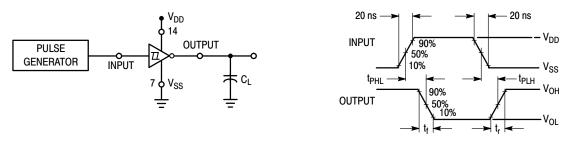


Figure 1. Switching Time Test Circuit and Waveforms

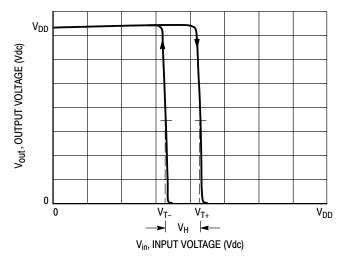
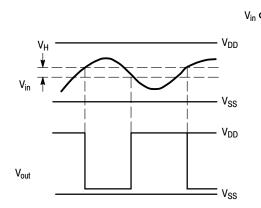
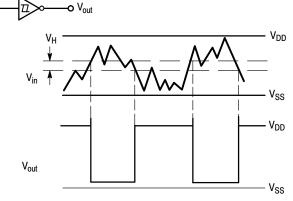


Figure 2. Typical Transfer Characteristics

APPLICATIONS

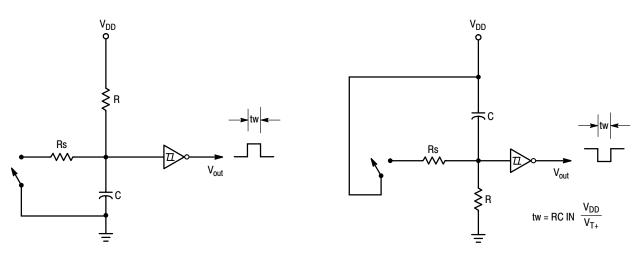




(a) Schmitt Triggers will square up inputs with slow rise and fall times.

(b) A Schmitt trigger offers maximum noise immunity in gate applications.





Useful as Pushbutton/Keyboard Debounce Circuit.

Figure 4. Monostable Multivibrator

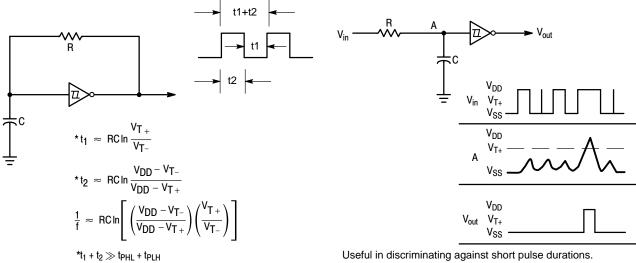
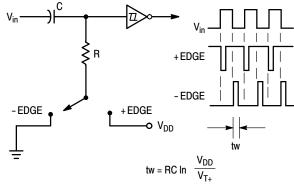


Figure 5. Astable Multivibrator

Useful in discriminating against short pulse durations.

Figure 6. Integrator



Useful as an edge detector circuit.

Figure 7. Differentiator

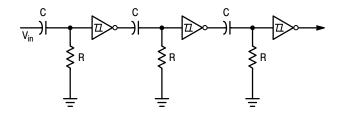
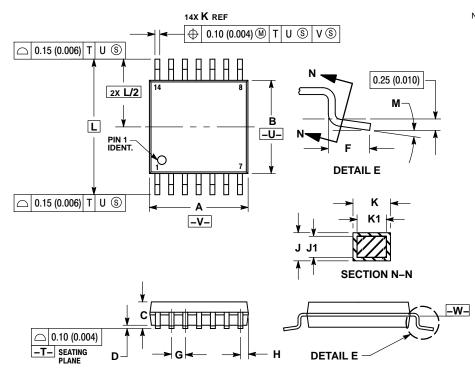


Figure 8. Positive Edge Time Delay Circuit

PACKAGE DIMENSIONS

TSSOP-14 CASE 948G **ISSUE B**

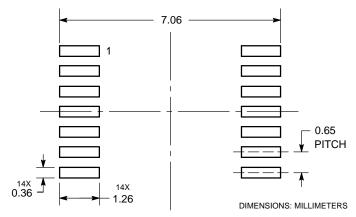


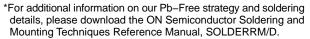
NOTES:

- DIES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EVOLUTION OF DOED OF DOING SHALL NOT
- EXCEED 0.15 (0.006) PER SIDE. 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL
- NOT EXCEED 0.25 (0.010) PER SIDE. 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION
- CONDITION. 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

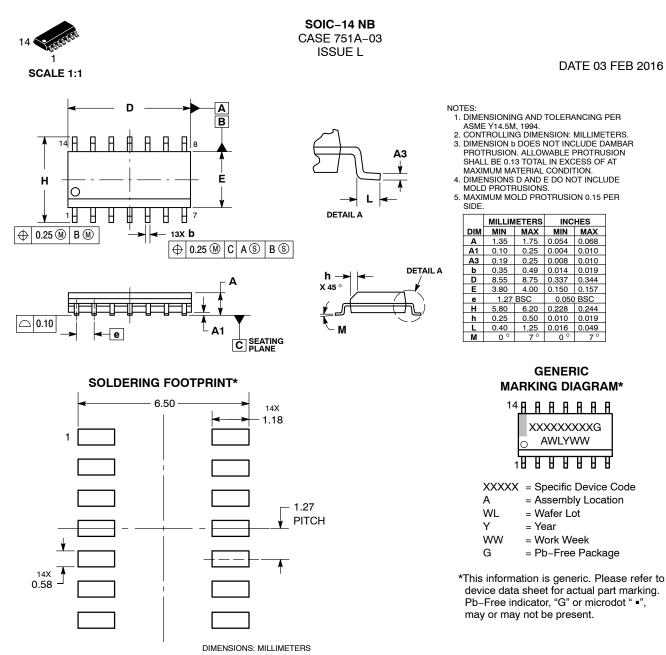
| | MILLIN | IETERS | INC | HES | |
|-----|----------|--------|-----------|-------|--|
| DIM | MIN MAX | | MIN | MAX | |
| Α | 4.90 | 5.10 | 0.193 | 0.200 | |
| В | 4.30 | 4.50 | 0.169 | 0.177 | |
| С | | 1.20 | | 0.047 | |
| D | 0.05 | 0.15 | 0.002 | 0.006 | |
| F | 0.50 | 0.75 | 0.020 | 0.030 | |
| G | 0.65 | BSC | 0.026 BSC | | |
| Н | 0.50 | 0.60 | 0.020 | 0.024 | |
| J | 0.09 | 0.20 | 0.004 | 0.008 | |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 | |
| κ | 0.19 | 0.30 | 0.007 | 0.012 | |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 | |
| Г | 6.40 BSC | | 0.252 | BSC | |
| М | 0 ° | 8 ° | 0 ° | 8 ° | |

SOLDERING FOOTPRINT*









*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

| DOCUMENT NUMBER: | 98ASB42565B | Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. | | | | | |
|---|---|---|-------------|--|--|--|--|
| DESCRIPTION: | SOIC-14 NB | | PAGE 1 OF 2 | | | | |
| ON Semiconductor reserves the right the suitability of its products for any pa | ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights or the rights of others. | | | | | | |

SOIC-14 CASE 751A-03 ISSUE L

DATE 03 FEB 2016

| STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE | STYLE 2: CANCELLED | STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE | STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE |
|---|---|---|---|
| STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE | STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE | STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE | STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE |

| DOCUMENT NUMBER: | 98ASB42565B | 65B Electronic versions are uncontrolled except when accessed directly from the Document Reposite Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. | | | | | | |
|---|--|--|-------------|--|--|--|--|--|
| DESCRIPTION: | SOIC-14 NB | | PAGE 2 OF 2 | | | | | |
| ON Semiconductor reserves the right the suitability of its products for any pa | ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the | | | | | | | |

© Semiconductor Components Industries, LLC, 2019

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor and the support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconducts harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized claim alleges that

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

٥